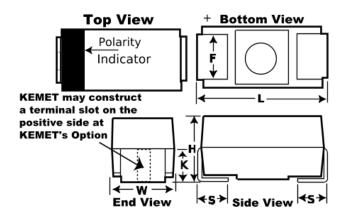


T495D477K006ZGE100

Obsolete

Tantalum, MnO2 Tantalum, 470 uF, 10%, 6.3 VDC, SMD, Molded, Low ESR, Surge Robust, 100 mOhms, 7343, 3.1mm



Dimensions		
Footprint	7343	
L	7.3mm +/-0.3mm	
W	4.3mm +/-0.3mm	
Н	2.8mm +/-0.3mm	
S	1.3mm +/-0.3mm	
F	2.4mm +/-0.1mm	
K	1.8mm TYP	

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	750

General Information		
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, Low ESR, Surge Robust	
Features	Low ESR, Surge Robust	
RoHS	Yes	
Termination	Gold	
AEC-Q200	No	
Notes	Old Part Number [Obsolete] Was B45106D4779K107.	

Specifications	
Capacitance	470 uF
Capacitance Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	15%
Failure Rate	N/A
ESR	0.1 Ohms (100kHz)
Ripple Current	1220 mAmps (25C), 1098 mAmps (85C), 488 mAmps (125C)
Leakage Current	29.6 uA

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.